





181NQ035/R-1 181NQ040/R-1 181NQ045/R-1 SCHOTTKY RECTIFIER



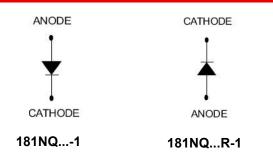
Features

- 175℃ T_J operation
- Unique high power, Half-Pak module
- Replaces three parallel DO-5' S
- Easier to mount and lower profile than DO-5' S
- High purity, high temperature epoxy encapsulation for enhanced
- mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Baseplate: Nickel plated; Terminals: Nickel plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Circuit Diagram

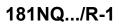


Maximum Ratings:

Characteristics	Symbol	Condition	Max.		Units
Peak Repetitive Reverse Voltage	V _{RRM}	-	35	181NQ035(R)-1	
Working Peak Reverse Voltage	VRWM		40	181NQ040(R)-1	V
DC Blocking Voltage	VR		45	181NQ045(R)-1	
Average Forward Current	I _{F(AV)}	50% duty cycle @T _C =125°C, rectangular wave form		180	A
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine pulse		3000	А
Non-Repetitive Avalanche Energy	E _{AS}	TJ=25℃,I _{AS} =36A,L=0.38mH		243	mJ
Repetitive Avalanche Current	I _{AR}	Current decaying linearly to zero in 1 μ sec Frequency limited by T _J max. V _A =1.5×V _R typical		36	А

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Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 180A, Pulse, T _J = 25 °C @ 360A, Pulse, T _J = 25 °C	0.58	0.66 0.80	V
	V _{F2}	@ 180A, Pulse, T _J = 125 °C @ 360A, Pulse, T _J = 125 °C	0.53 0.63	0.56 0.69	V
Reverse Current*	I _{R1}	$@V_R = rated V_R T_J = 25 \circ C$	0.1	15	mA
	I _{R2}	$@V_R$ = rated $V_R T_J$ = 125 °C	20	135	mA
Junction Capacitance	Ст	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	6500	7800	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

* Pulse width < 300 $\mu s, \ duty \ cycle < 2\%$

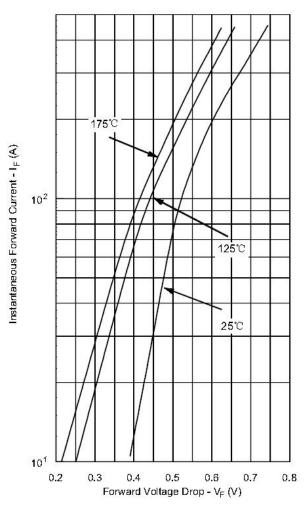
Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specifi	Units	
Junction Temperature	TJ	-	-55 to +175		°C
Storage Temperature	T _{stg}	-	-55 to +175		°C
Typical Thermal Resistance Junction to Case	$R_{ ext{ heta}JC}$	DC operation	0.30		°C/W
Typical Thermal Resistance, case to Heat Sink	$R_{ hetacs}$	Mounting surface, smooth and greased	0.15		°C/W
Mounting Torque	Тм	Non-lubricated threads	Mounting Torque	23(min) 29(max)	Kg-cm
			Terminal Torque	35(min) 46(max)	
Approximate Weight	wt	-	25.6 0		
Case Style	PRM1-1				

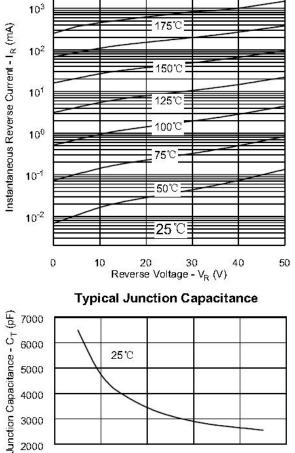
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Ratings and Characteristics Curves



Typical Forward Characteristics



Typical Reverse Characteristics

1st row SS YYWW 2nd row 181NQ035-1 SS = SS YY = Year WW = Week

Where XXXX is YYWW

40

Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information

Device	Package	Shipping	
181NQ SERIES	PRM1-1(Pb-Free)	27pcs/ box	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

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Marking Diagram

SS XXXX

181NQ035-1

10

20

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Reverse Voltage - V_R (V)

50

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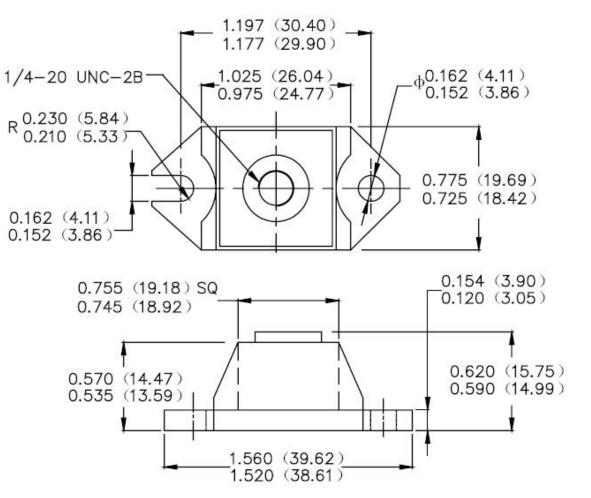


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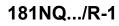
Technical Data Data Sheet N1172, Rev. A

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